

SPDT SWITCH GaAs MMIC

■ GENERAL DESCRIPTION

■ PACKAGE OUTLINE

NJG1649HB6 is a GaAs SPDT switch IC suited for W-LAN, Bluetooth and sub-microwave applications.

This device can operate a single bit control signal from +1.3V.

The ultra-small & ultra-thin USB8-B6 package is adopted.



NJG1649HB6

■ FEATURES

 Single bit control +1.3V min. Low voltage operation +2.5~+4.5V

Low insertion loss $0.35dB \text{ typ. } @f=1.0GHz, P_{IN}=23dBm, V_{DD}=2.7V$ 0.40dB typ. @f=2.0GHz, P_{IN}=23dBm, V_{DD}=2.7V 0.45dB typ. @f=2.5GHz, P_{IN} =23dBm, V_{DD} =2.7V

● Input power at 0.2dB compression point 30dBm typ. @f=2.5GHz, V_{DD}=2.7V

High isolation 27dB typ. @f=1.0GHz, P_{IN}=23dBm, V_{DD}=2.7V

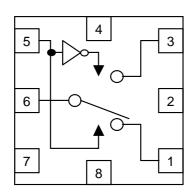
22dB typ. @f=2.0GHz, P_{IN}=23dBm, V_{DD}=2.7V 20dB typ. @f=2.5GHz, P_{IN} =23dBm, V_{DD} =2.7V

Small & thin package

USB8-B6 (Package size: 1.5x1.5x0.55mm)

■ PIN CONFIGURATION

USB8-B6 Type (TOP VIEW)



Pin connection

- Ρ1 1.
- 2. **GND**
- P2 3.
- **GND** 4.
- **VCTL** 5.
- PC 6.
- **VDD** 7.
- **GND** 8.

■ TRUTH TABLE

Control Voltage: "H"=VCTL(H), "L"=VCTL(L)

VCTL	PATH
Н	P1-PC
L	P2-PC

NOTE: The information on this datasheet is subject to change without notice.

■ ABSOLUTE MAXIMUM RATINGS

 $(T_a=+25^{\circ}C, Z_s=Z_l=50\Omega)$

PARAMETER	SYMBOL	CONDITIONS	CONDITIONS	UNITS
RF input power	P _{IN}	V _{DD} =2.7V, V _{CTL} =0V/1.8V	32	dBm
Supply voltage	V_{DD}	VDD terminal	5.0	V
Control voltage	V _{CTL}	VCTL terminal	5.0	V
Power dissipation	P_D	On PCB board	160	mW
Operating temp.	T_{opr}		-40~+85	°C
Storage temp.	T_{stg}		-55~+150	°C

■ ELECTRICAL CHARACTERISTICS

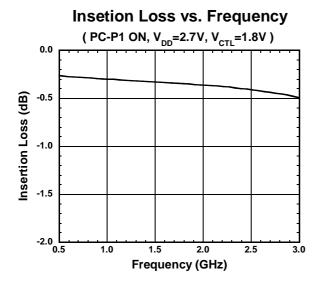
 $(General\ conditions:\ T_a=+25^{\circ}C,\ V_{CTL\ (L)}=0V,\ V_{CTL\ (H)}=1.8V,\ Z_s=Z_l=50\Omega\ with\ application\ circuit)$

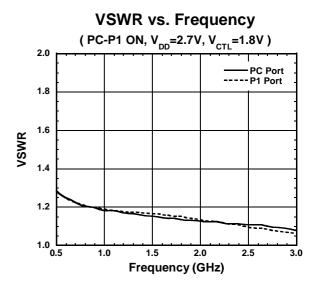
PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply voltage	V_{DD}		2.5	2.7	4.5	V
Operating current	I_{DD}	f=2.5GHz, P _{IN} =23dBm	-	20	40	μΑ
Control voltage (LOW)	V _{CTL (L)}		0	-	0.4	V
Control voltage (HIGH)	V _{CTL (H)}		1.3	1.8	4.5	V
Control current	I _{CTL}		-	3	10	μА
Insertion loss 1	LOSS1	f=1.0GHz, P _{IN} =23dBm	-	0.35	0.50	dB
Insertion loss 2	LOSS2	f=2.0GHz, P _{IN} =23dBm	-	0.40	0.55	dB
Insertion loss 3	LOSS3	f=2.5GHz, P _{IN} =23dBm	-	0.45	0.60	dB
Isolation 1	ISL1	f=1.0GHz, P _{IN} =23dBm	24	27	-	dB
Isolation 2	ISL2	f=2.0GHz, P _{IN} =23dBm	19	22	-	dB
Isolation 3	ISL3	f=2.5GHz, P _{IN} =23dBm	17	20	-	dB
Input power at 0.2dB compression point	P _{-0.2dB}	f=2.5GHz	28	30	-	dBm
VSWR	VSWR	f=0.1~2.5GHz, ON State	-	1.1	1.3	
Switching time	T _{SW}		-	1	5	μS

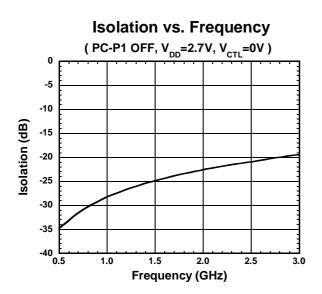
■ TERMINAL INFORMATION

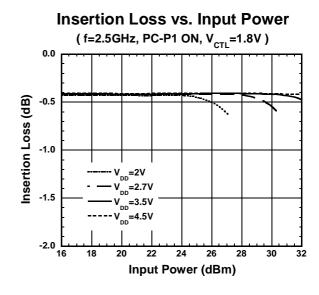
No.	SYMBOL	DESCRIPTION
1	P1	RF port. This port is connected to PC port by control voltage of +1.3~4.5V(V _{CTL(H)}) at 5th pin. In order to block DC bias voltage of internal circuit, an external capacitor is required.
2	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for good RF performance.
3	P2	RF port. This port is connected to PC port by control voltage of +0.0~0.4V(V _{CTL(L)}) at 5th pin. In order to block DC bias voltage of internal circuit, an external capacitor is required.
4	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for good RF performance.
5	VCTL	Control port. This terminal is set to +1.3V~4.5V of logical high level for ON state between PC and P1 RF ports, and set to +0.0~0.4V of logical low level for ON state between PC and P2 RF ports.
6	PC	Common RF port. This PC port is connected to P1 or P2 by logical control voltage of VCTL. In order to block DC bias voltage of internal circuit, an external capacitor is required.
7	VDD	A supply voltage terminal (+2.5~+4.5V). Please place a bypass capacitor between this and GND for avoiding RF noise from outside.
8	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for good RF performance.

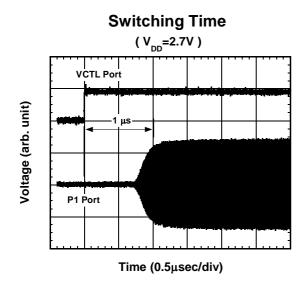
ELECTRICAL CHARACTERISTICS (With Application circuit, Loss of external circuit are excluded)



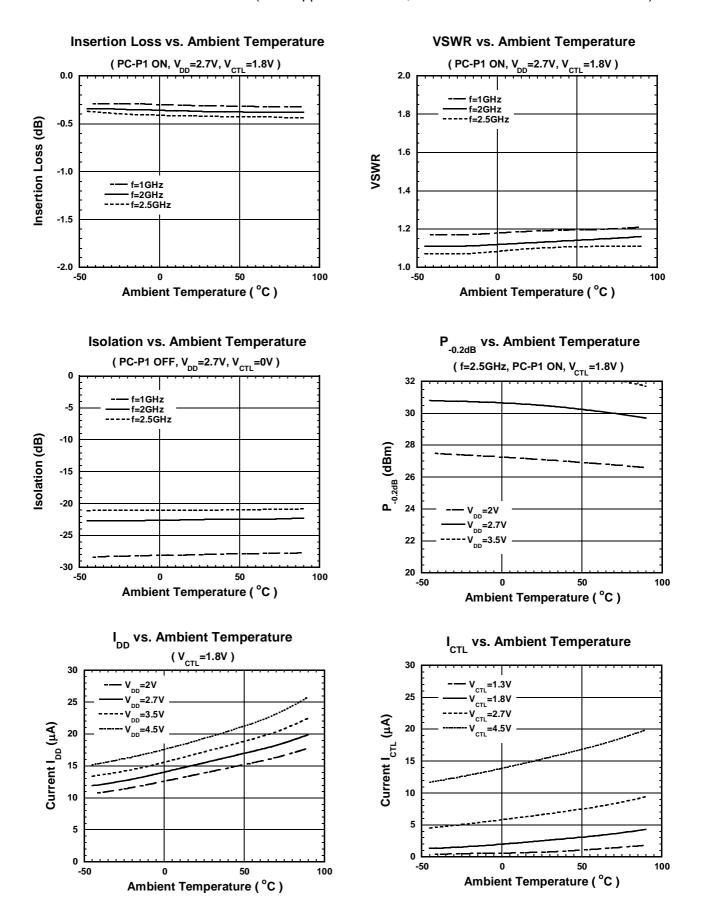






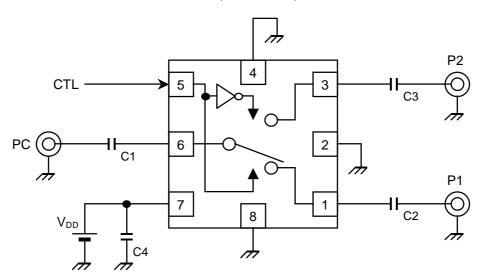


ELECTRICAL CHARACTERISTICS (With Application circuit, Loss of external circuit are excluded)



■ APPLICATION CIRCUIT



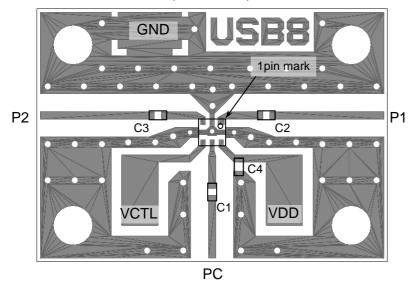


■ PARTS LIST

Parts ID	Value	Notes
C1, C2, C3	56pF	Murata
C4	1000pF	(GRM15)

TEST PCB LAYOUT

(TOP VIEW)



PCB SIZE=19.4x14.0mm PBC: FR-4, t=0.2mm CAPACITOR: size 1005 STLIPLINE=0.4mm

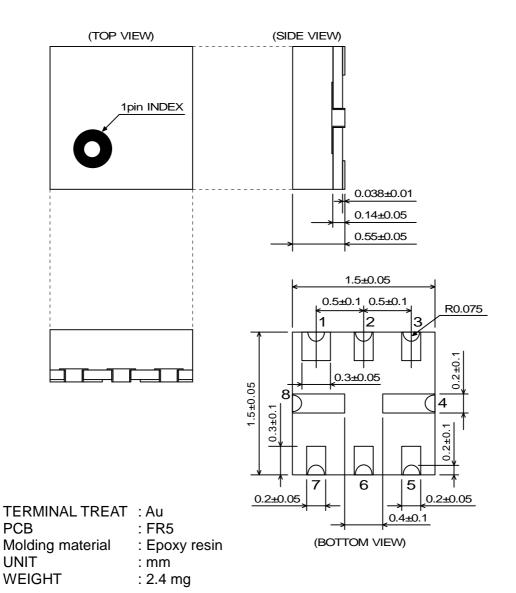
Losses of PCB, capacitors and connectors

Frequency (GHz)	Loss (dB)
1.0	0.21
2.0	0.31
2.5	0.36

PRECAUTIONS

- [1]The DC blocking capacitors have to be placed at RF terminal of P1, P2 and PC. Please choose appropriate capacitance values to the application frequency.
- [2]For avoiding the degradation of RF performance, please place bypass capacitor(C4) as close as possible to each terminal.
- [3]For good isolation, the GND terminal must be connected with the ground plane of substrate, and through-holes for GND should be placed near by the IC.

■ PACKAGE OUTLINE (USB8-B6)



Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

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 - Aerospace Equipment
 - · Equipment Used in the Deep Sea
 - Power Generator Control Equipment (nuclear, steam, hydraulic, etc.)
 - · Life Maintenance Medical Equipment
 - · Fire Alarms / Intruder Detectors
 - Vehicle Control Equipment (automotive, airplane, railroad, ship, etc.)
 - Various Safety Devices
 - Traffic control system
 - Combustion equipment

In case your company desires to use this product for any applications other than general electronic equipment mentioned above, make sure to contact our company in advance. Note that the important requirements mentioned in this section are not applicable to cases where operation requirements such as application conditions are confirmed by our company in writing after consultation with your company.

- 6. We are making our continuous effort to improve the quality and reliability of our products, but semiconductor products are likely to fail with certain probability. In order to prevent any injury to persons or damages to property resulting from such failure, customers should be careful enough to incorporate safety measures in their design, such as redundancy feature, fire containment feature and fail-safe feature. We do not assume any liability or responsibility for any loss or damage arising from misuse or inappropriate use of the products.
- 7. The products have been designed and tested to function within controlled environmental conditions. Do not use products under conditions that deviate from methods or applications specified in this datasheet. Failure to employ the products in the proper applications can lead to deterioration, destruction or failure of the products. We shall not be responsible for any bodily injury, fires or accident, property damage or any consequential damages resulting from misuse or misapplication of the products.
- 8. Quality Warranty
 - 8-1. Quality Warranty Period
 - In the case of a product purchased through an authorized distributor or directly from us, the warranty period for this product shall be one (1) year after delivery to your company. For defective products that occurred during this period, we will take the quality warranty measures described in section 8-2. However, if there is an agreement on the warranty period in the basic transaction agreement, quality assurance agreement, delivery specifications, etc., it shall be followed.
 - 8-2. Quality Warranty Remedies
 - When it has been proved defective due to manufacturing factors as a result of defect analysis by us, we will either deliver a substitute for the defective product or refund the purchase price of the defective product.
 - Note that such delivery or refund is sole and exclusive remedies to your company for the defective product.
 - 8-3. Remedies after Quality Warranty Period
 - With respect to any defect of this product found after the quality warranty period, the defect will be analyzed by us. On the basis of the defect analysis results, the scope and amounts of damage shall be determined by mutual agreement of both parties. Then we will deal with upper limit in Section 8-2. This provision is not intended to limit any legal rights of your company.
- 9. Anti-radiation design is not implemented in the products described in this document.
- 10. The X-ray exposure can influence functions and characteristics of the products. Confirm the product functions and characteristics in the evaluation stage.
- 11. WLCSP products should be used in light shielded environments. The light exposure can influence functions and characteristics of the products under operation or storage.
- 12. Warning for handling Gallium and Arsenic (GaAs) products (Applying to GaAs MMIC, Photo Reflector). These products use Gallium (Ga) and Arsenic (As) which are specified as poisonous chemicals by law. For the prevention of a hazard, do not burn, destroy, or process chemically to make them as gas or power. When the product is disposed of, please follow the related regulation and do not mix this with general industrial waste or household waste.
- 13. Please contact our sales representatives should you have any questions or comments concerning the products or the technical information.



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